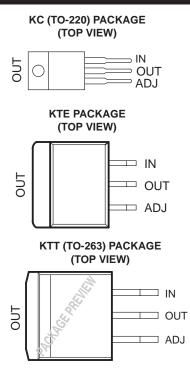
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- Output Adjustable From 1.25 V to 125 V When Used With an External Resistor Divider
- 700-mA Output Current
- Full Short-Circuit, Safe-Operating-Area, and Thermal-Shutdown Protection
- 0.001%/V Typical Input Voltage Regulation
- 0.15% Typical Output Voltage Regulation
- 76-dB Typical Ripple Rejection

description/ordering information

The TL783 is an adjustable three-terminal high-voltage regulator with an output range of 1.25 V to 125 V and a DMOS output transistor capable of sourcing more than 700 mA. It is designed for use in high-voltage applications where standard bipolar regulators cannot be used. Excellent performance specifications, superior to those of most bipolar regulators, are achieved through circuit design and advanced layout techniques.



As a state-of-the-art regulator, the TL783 combines standard bipolar circuitry with high-voltage double-diffused MOS transistors on one chip, to yield a device capable of withstanding voltages far higher than standard bipolar integrated circuits. Because of its lack of secondary-breakdown and thermal-runaway characteristics usually associated with bipolar outputs, the TL783 maintains full overload protection while operating at up to 125 V from input to output. Other features of the device include current limiting, safe-operating-area (SOA) protection, and thermal shutdown. Even if ADJ is disconnected inadvertently, the protection circuitry remains functional.

Only two external resistors are required to program the output voltage. An input bypass capacitor is necessary only when the regulator is situated far from the input filter. An output capacitor, although not required, improves transient response and protection from instantaneous output short circuits. Excellent ripple rejection can be achieved without a bypass capacitor at the adjustment terminal.

Тј	PACKA	3E†	ORDERABLE PART NUMBER	TOP-SIDE MARKING
0°C to 125°C	Power Flex (KTE)	Reel of 2000	TL783CKTER	TL783
	TO 000 (1/TT)	Tube of 50	TL783CKTT	
	TO-263 (KTT)	Reel of 1000	TL783CKTTR	PREVIEW
	TO-220 (KC)	Tube of 50	TL783CKC	TL783C

ORDERING INFORMATION

[†] Package drawings, standard packing quantities, thermal data, symbolization, and PCB design guidelines are available at www.ti.com/sc/package.



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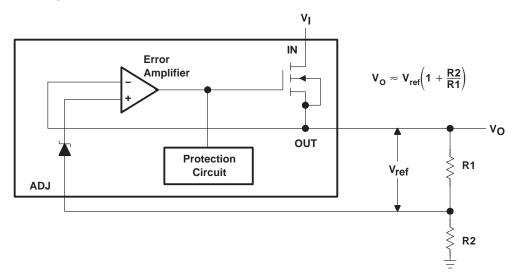
PRODUCTION DATA information is current as of publication date. Products conform to specifications per the terms of Texas Instruments standard warranty. Production processing does not necessarily include testing of all parameters.



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functional block diagram



absolute maximum ratings over operating temperature range (unless otherwise noted)[†]

Input-to-output differential voltage, V _I – V _O 125 V	'
Operating virtual junction temperature, T _J 150°C	,
Storage temperature range, T _{stg}	,

[†] Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

package thermal data (see Note 1)

PACKAGE	BOARD	θJC	θ _{JP} ‡	ΑL ^θ
Power Flex (KTE)	High K, JESD 51-5	-	2.7°C/W	23°C/W
TO-263 (KTT)	High K, JESD 51-5	TBD	TBD	TBD
TO-220 (KC)	High K, JESD 51-5	17°C/W	3°C/W	19°C/W

NOTE 1: Maximum power dissipation is a function of $T_J(max)$, θ_{JA} , and T_A . The maximum allowable power dissipation at any allowable ambient temperature is $P_D = (T_J(max) - T_A)/\theta_{JA}$. Operating at the absolute maximum T_J of 150°C can affect reliability. Due to variations in individual device electrical characteristics and thermal resistance, the built-in thermal overload protection may be activated at power levels slightly above or below the rated dissipation.

[‡] For packages with exposed thermal pads, such as QFN, PowerPAD, or PowerFLEX, θ_{JP} is defined as the thermal resistance between the die junction and the bottom of the exposed pad.

recommended operating conditions

			MIN	MAX	UNIT
$V_I - V_O$	Input-to-output voltage differential			125	V
IO	Output current		15	700	mA
Тј	Operating virtual junction temperature	TL783C	0	125	°C



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		TL783C					
PARAMETER		MIN	TYP	MAX	UNIT		
Input voltage		Distant distant attact	T _J = 25°C		0.001	0.01	0/ 1/
regulation‡	$V_{I} - V_{O} = 20 V \text{ to } 125 V,$	$P \le$ rated dissipation	$T_J = 0^{\circ}C$ to $125^{\circ}C$		0.004	0.02	%/V
Ripple rejection	$\Delta V_{I(PP)} = 10 V,$	V _O = 10 V,	f = 120 Hz	66	76		dB
		T. 0500	$V_{O} \le 5 V$		7.5	25	mV
Output voltage	I _O = 15 mA to 700 mA,	T _J = 25°C	$V_{O} \ge 5 V$		0.15	0.5	%
regulation		Distant difference the	$V_{O} \le 5 V$		20	70	mV
	I _O = 15 mA to 700 mA,	$P \le$ rated dissipation	$V_{O} \ge 5 V$		0.3	1.5	%
Output voltage change with temperature					0.4		%
Output voltage long-term drift	1000 hours at T _J = 125°C,	V _I – V _O = 125 V			0.2		%
Output noise voltage	f = 10 Hz to 10 kHz,	TJ = 25°C			0.003		%
Minimum output current to maintain regulation	V _I – V _O = 125 V					15	mA
	$V_{I} - V_{O} = 25 V,$	t = 1 ms			1100		
Deale and an entered	$V_{I} - V_{O} = 15 V,$	t = 30 ms			715		
Peak output current	$V_{I} - V_{O} = 25 V,$	t = 30 ms			900		mA
	$V_{I} - V_{O} = 125 V,$	t = 30 ms		100	250		
ADJ input current					83	110	μΑ
Change in ADJ input current	$V_{I} - V_{O} = 15 V$ to 125 V,	I_{O} = 15 mA to 700 mA,	P ≤ rated dissipation		0.5	5	μA
Reference voltage (OUT to ADJ)	$V_{I} - V_{O} = 10 V$ to 125 V, See Note 2	I _O = 15 mA to 700 mA,	$P \leq$ rated dissipation,	1.2	1.27	1.3	V

electrical characteristics at $V_I - V_O = 25 V$, $I_O = 0.5 A$, $T_J = 0^{\circ}C$ to $125^{\circ}C$ (unless otherwise noted)

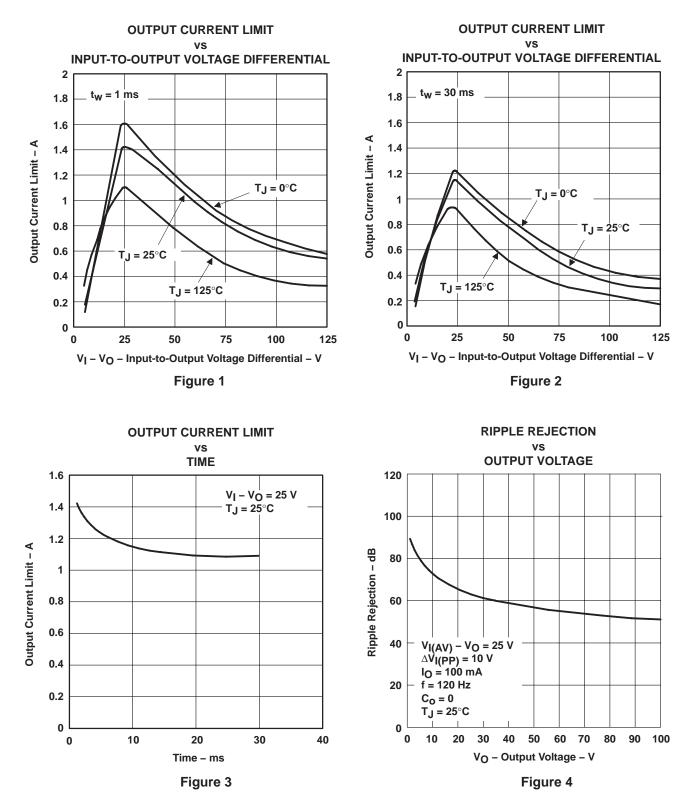
[†] Pulse-testing techniques maintain the junction temperature as close to the ambient temperature as possible. Thermal effects must be taken into account separately.

[‡] Input voltage regulation is expressed here as the percentage change in output voltage per 1-V change at the input.

NOTE 2: Due to the dropout voltage and output current-limiting characteristics of this device, output current is limited to less than 700 mA at input-to-output voltage differentials of less than 25 V.



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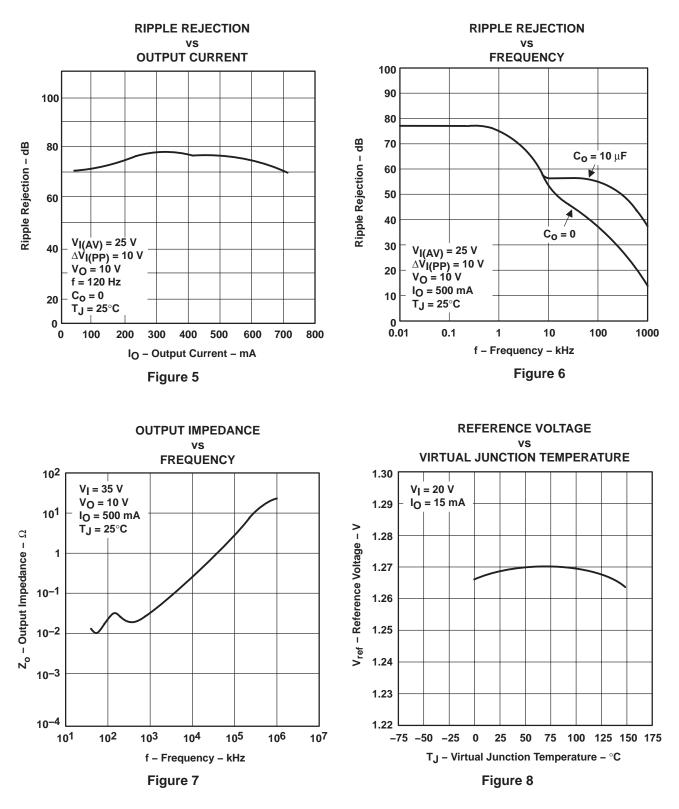


TYPICAL CHARACTERISTICS



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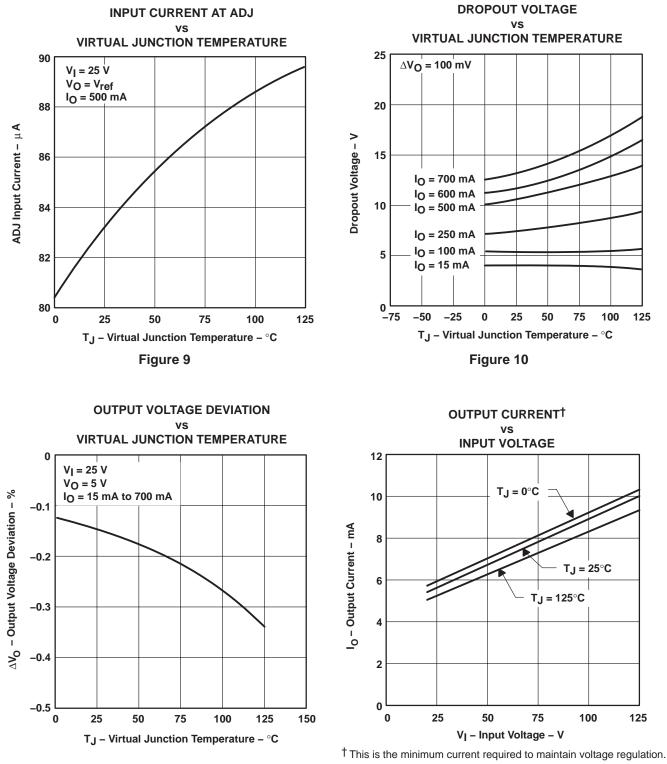
TYPICAL CHARACTERISTICS[†]



[†] Data at high and low temperatures are applicable only within the recommended operating free-air temperature ranges of the various devices.



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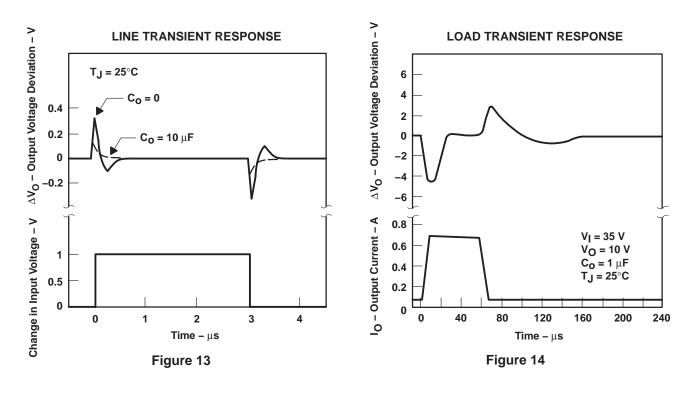
TYPICAL CHARACTERISTICS

Figure 11

Figure 12



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TYPICAL CHARACTERISTICS

DESIGN CONSIDERATIONS

The internal reference (see functional block diagram) generates 1.25 V nominal (V_{ref}) between OUT and ADJ. This voltage is developed across R1 and causes a constant current to flow through R1 and the programming resistor R2, giving an output voltage of:

 $V_{O} = V_{ref} (1 + R2/R1) + I_{I(ADJ)} (R2)$

or

 $V_{O} \approx V_{ref} (1 + R2/R1)$

The TL783 was designed to minimize the input current at ADJ and maintain consistency over line and load variations, thereby minimizing the associated (R2) error term.

To maintain $I_{I(ADJ)}$ at a low level, all quiescent operating current is returned to the output terminal. This quiescent current must be sunk by the external load and is the minimum load current necessary to prevent the output from rising. The recommended R1 value of 82 Ω provides a minimum load current of 15 mA. Larger values can be used when the input-to-output differential voltage is less than 125 V (see the output-current curve in Figure 12) or when the load sinks some portion of the minimum current.



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DESIGN CONSIDERATIONS

bypass capacitors

The TL783 regulator is stable without bypass capacitors; however, any regulator becomes unstable with certain values of output capacitance if an input capacitor is not used. Therefore, the use of input bypassing is recommended whenever the regulator is located more than four inches from the power-supply filter capacitor. A $1-\mu F$ tantalum or aluminum electrolytic capacitor usually is sufficient.

Adjustment-terminal capacitors are not recommended for use on the TL783 because they can seriously degrade load transient response, as well as create a need for extra protection circuitry. Excellent ripple rejection presently is achieved without this added capacitor.

Due to the relatively low gain of the MOS output stage, output voltage dropout may occur under large-load transient conditions. The addition of an output bypass capacitor greatly enhances load transient response and prevents dropout. For most applications, it is recommended that an output bypass capacitor be used, with a minimum value of:

 $C_0 (\mu F) = 15/V_0$

Larger values provide proportionally better transient-response characteristics.

protection circuitry

The TL783 regulator includes built-in protection circuits capable of guarding the device against most overload conditions encountered in normal operation. These protective features are current limiting, safe-operating-area protection, and thermal shutdown. These circuits protect the device under occasional fault conditions only. Continuous operation in the current limit or thermal shutdown mode is not recommended.

The internal protection circuits of the TL783 protect the device up to maximum-rated V_I as long as certain precautions are taken. If V_I is switched on instantaneously, transients exceeding maximum input ratings may occur, which can destroy the regulator. Usually, these are caused by lead inductance and bypass capacitors causing a ringing voltage on the input. In addition, when rise times in excess of 10 V/ns are applied to the input, a parasitic npn transistor in parallel with the DMOS output can be turned on, causing the device to fail. If the device is operated over 50 V and the input is switched on, rather than ramped on, a low-Q capacitor, such as tantalum or aluminum electrolytic, should be used, rather than ceramic, paper, or plastic bypass capacitors. A Q factor of 0.015, or greater, usually provides adequate damping to suppress ringing. Normally, no problems occur if the input voltage is allowed to ramp upward through the action of an ac line rectifier and filter network.

Similarly, when an instantaneous short circuit is applied to the output, both ringing and excessive fall times can result. A tantalum or aluminum electrolytic bypass capacitor is recommended to eliminate this problem. However, if a large output capacitor is used, and the input is shorted, addition of a protection diode may be necessary to prevent capacitor discharge through the regulator. The amount of discharge current delivered is dependent on output voltage, size of capacitor, and fall time of V_{I} . A protective diode (see Figure 17) is required only for capacitance values greater than:

 $C_0 (\mu F) = 3 \times 10^4 / (V_0)^2$

Care always should be taken to prevent insertion of regulators into a socket with power on. Power should be turned off before removing or inserting regulators.



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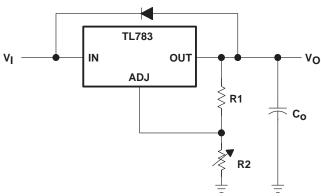


Figure 15. Regulator With Protective Diode

load regulation

The current-set resistor (R1) should be located close to the regulator output terminal, rather than near the load. This eliminates long line drops from being amplified, through the action of R1 and R2, to degrade load regulation. To provide remote ground sensing, R2 should be near the load ground.

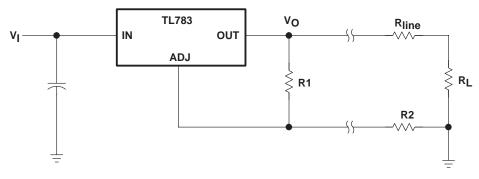
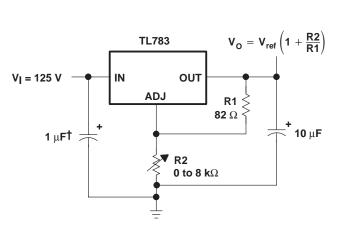


Figure 16. Regulator With Current-Set Resistor



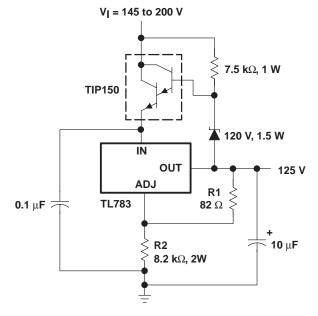
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APPLICATION INFORMATION



[†] Needed if device is more than 4 inches from filter capacitor

Figure 17. 1.25-V to 115-V Adjustable Regulator





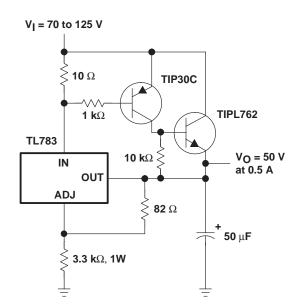


Figure 19. 50-V Regulator With Current Boost

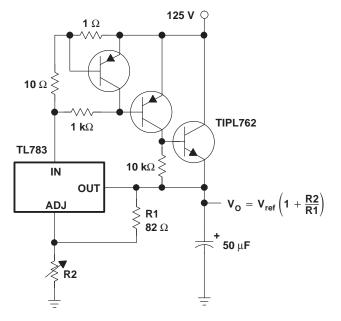


Figure 20. Adjustable Regulator With Current Boost and Current Limit



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APPLICATION INFORMATION

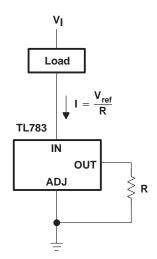


Figure 21. Current-Sinking Regulator

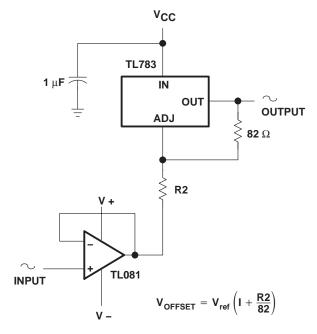
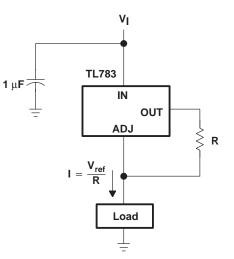
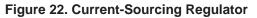


Figure 23. High-Voltage Unity-Gain Offset Amplifier





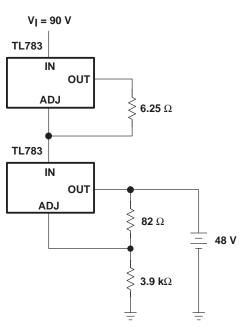


Figure 24. 48-V, 200-mA Float Charger



PACKAGING INFORMATION

Orderable Device	Status ⁽¹⁾	Package Type	Package Drawing	Pins	Package Qty	Eco Plan ⁽²⁾	Lead/Ball Finish	MSL Peak Temp ⁽³⁾
TL783CKC	ACTIVE	TO-220	KC	3	50	TBD	CU SNPB	Level-NC-NC-NC
TL783CKCE3	ACTIVE	TO-220	KC	3	50	Pb-Free (RoHS)	CU SN	Level-NC-NC-NC
TL783CKTER	ACTIVE	PFM	KTE	3	2000	TBD	CU SNPB	Level-1-220C-UNLIM

⁽¹⁾ The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS) or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details. TBD: The Pb-Free/Green conversion plan has not been defined.

Pb-Free (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

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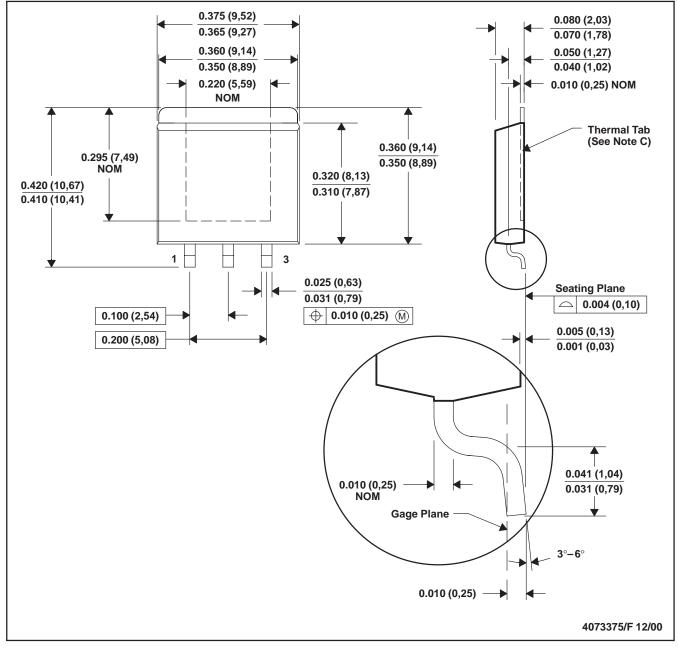
⁽³⁾ MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

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PowerFLEX[™] PLASTIC FLANGE-MOUNT



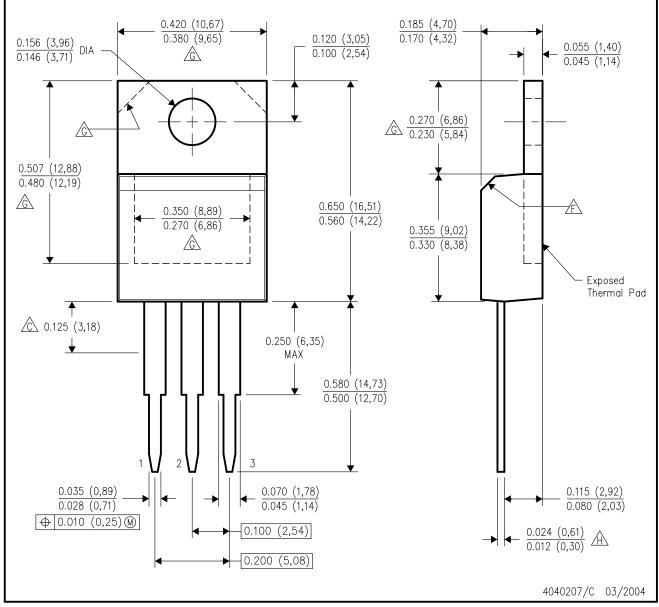
- NOTES: A. All linear dimensions are in inches (millimeters).
 - B. This drawing is subject to change without notice.
 - C. The center lead is in electrical contact with the thermal tab.
 - D. Dimensions do not include mold protrusions, not to exceed 0.006 (0,15).
 - E. Falls within JEDEC MO-169

KTE (R-PSFM-G3)

PowerFLEX is a trademark of Texas Instruments.

KC (R-PSFM-T3)

PLASTIC FLANGE-MOUNT PACKAGE



NOTES:

- A. All linear dimensions are in inches (millimeters).B. This drawing is subject to change without notice.
- Lead dimensions are not controlled within this area.

D. All lead dimensions apply before solder dip.

- E. The center lead is in electrical contact with the mounting tab.
- \frown The chamfer is optional.
- A Thermal pad contour optional within these dimensions.
- \triangle Falls within JEDEC TO-220 variation AB, except minimum lead thickness.



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